

SiC - Photodiode JEC 0,1*



- characteristics :
- ◆ SiC-Photodiode with integrated filter
 - ◆ *-filter option for UV-C, UV-BC, UV-B and UV-A
 - ◆ active area 0,055 mm²
 - ◆ TO 5-package
 - ◆ components are in conformity with RoHS and WEEE

- applications :
- ◆ UV-measurement only
 - ◆ control of sterilization lamps
 - ◆ flame detection
 - ◆ sun measurement

absolute maximum ratings:

reverse voltage	20	V
operating temperature range	- 25 °C ... 70	°C
storage temperature range	-40 °C ... 100	°C
welding temperature (3s)	260	°C

technical data :

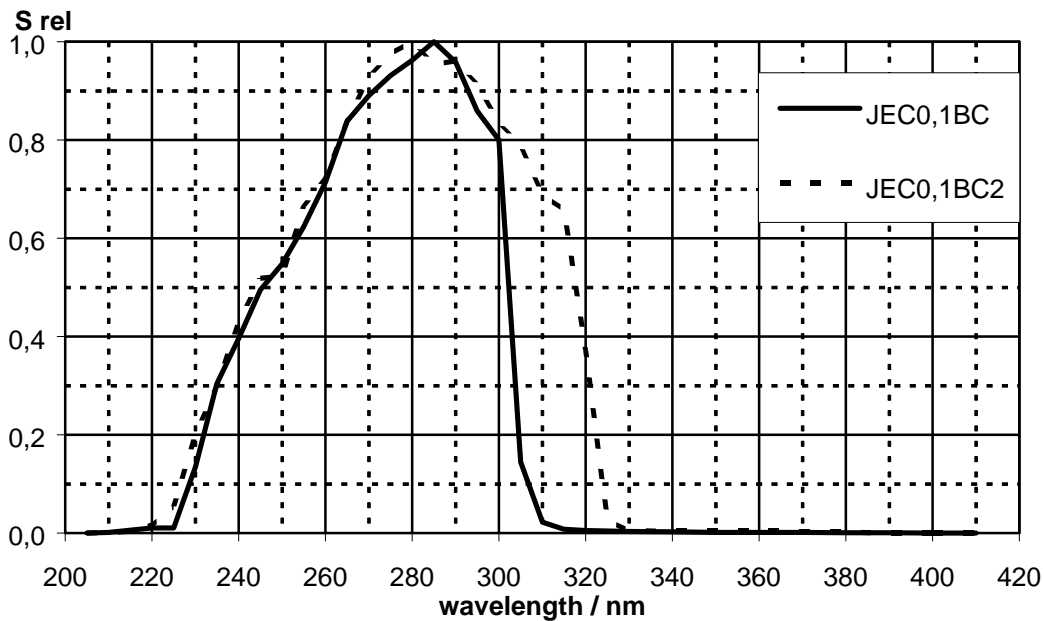
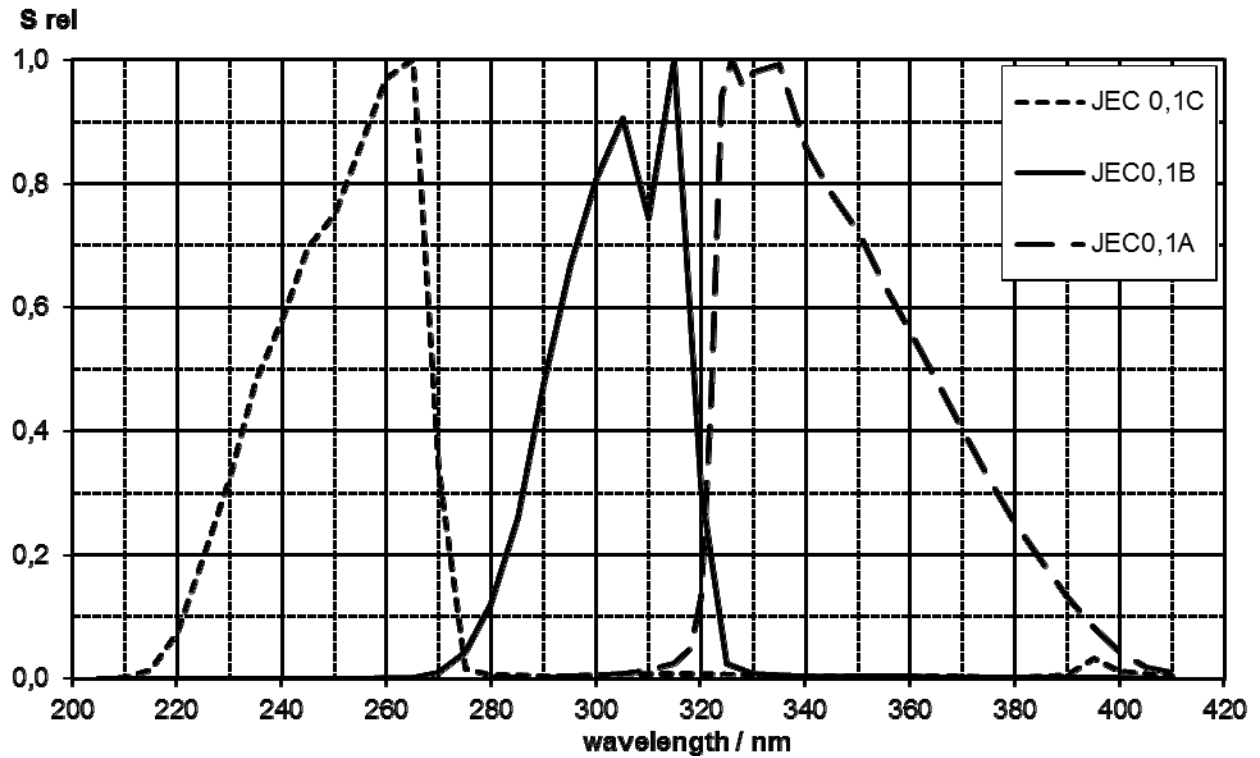
common test conditions, if not otherwise specified: $\gamma_a = 25 \text{ °C}$, $V_R = 0V$

parameter	test-conditions	* - filter option					units	
		JE 0,1C	JEC 0,1BC	JEC0,1BC2	JEC 0,1B	JEC 0,1A		
name of component		JE 0,1C	JEC 0,1BC	JEC0,1BC2	JEC 0,1B	JEC 0,1A		
active area		0,25 x 0,25					mm ²	
spectral range	S=0,1 • S _{max}							
		λ_{\min}	220	230	225	280	320	nm
		λ_{\max}	275	305	320	325	395	
maximum of spectral responsivity λ_p	S = S _{max}	265	285	280	315	330	nm	
absolute spectral responsivity	$\lambda = \lambda_p$	0,1	0,12	0,12	0,08	0,06	A/W	
dark current I _D	V _R = 1 V	1					fA	
capacitance		21					pF	
height of component H		4,5			6,8		mm	

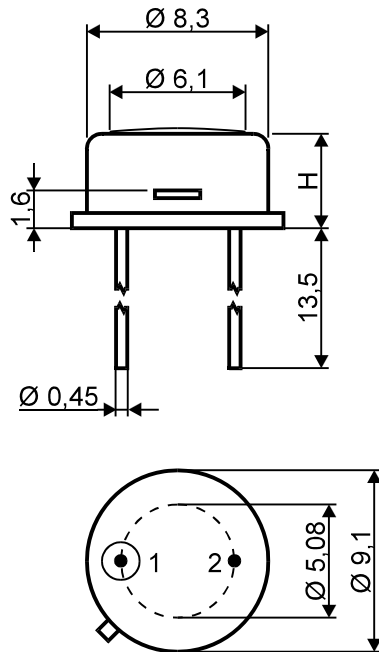
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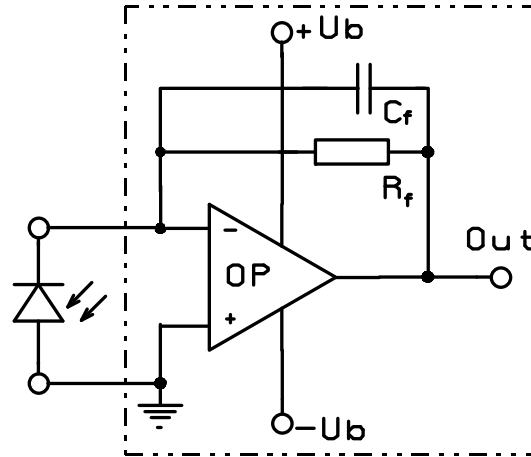
relative spectral response



package dimensions



application example



- 1 Katode
- 2 Anode & Case

The application example shows a typical circuit. R_f is responsible for the gain of the circuit. C_f compensates the reverse junction capacitance of the photodiode and input capacitance of the OPA. The exact value of C_f depends on R_f , used OPA and capacitance of the circuit. A typical value is 1 pF.